Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

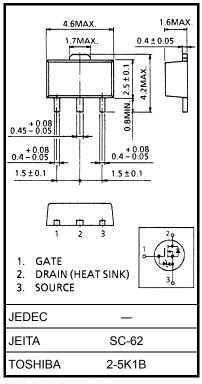
# 2SK3471

Switching Regulator and DC-DC Converter Applications

- Low drain-source ON-resistance: R<sub>DS (ON)</sub> = 10 Ω (typ.)
- High forward transfer admittance: |Y<sub>fs</sub>| = 0.4 S (typ.)
- Low leakage current: I<sub>DSS</sub> = 100 μA (max) (V<sub>DS</sub> = 500 V)
- Enhancement model:  $V_{th}$  = 2.0 to 4.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	500	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		V <sub>DGR</sub>	500	V
Gate-source voltage		V <sub>GSS</sub>	±30	V
Drain current	DC (Note 1)	I <sub>D</sub>	0.5	А
	Pulse (Note 1)	I <sub>DP</sub>	1.5	A
Drain power dissipation		PD	0.5	W
Drain power dissipation (Note 2)		PD	1.5	W
Single pulse avalanche energy (Note 3)		E <sub>AS</sub>	14.3	mJ
Avalanche current		I <sub>AR</sub>	0.5	А
Repetitive avalanche energy (Note 4)		E <sub>AR</sub>	0.05	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature range		T <sub>stg</sub>	-55 to150	°C



Weight: 0.05 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	250	°C/W	

Note 1: Ensure that the channel temperature does not exceed 150°C

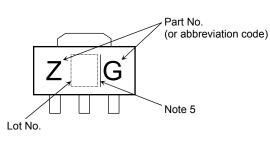
Note 2: Mounted on a ceramic substrate (25.4 mm × 25.4 mm × 0.8 mm)

Note 3: V\_{DD} = 90 V, T\_{ch} = 25 ^{\circ}C (initial), L = 100 mH, R\_G = 25  $\Omega,~I_{AR}$  = 0.5 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

#### Marking



Note 5: A line beside a Lot No. identifies the indication of product Labels.

Without a line: [[Pb]]/INCLUDES > MCV With a line: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

## **Electrical Characteristics (Ta = 25°C)**

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm 25~V,~V_{DS}=0~V$		_	±10	μA
Gate-source brea	akdown voltage	V (BR) GSS	$I_G=\pm 10~\mu A,~V_{DS}=0~V$	±30			V
Drain cut-OFF current		I <sub>DSS</sub>	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			100	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	500			V
Gate threshold v	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	resistance	R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 0.25 \text{ A}$		10	18	Ω
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.25 \text{ A}$	0.2	0.4		S
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		75		pF
Reverse transfer capacitance		C <sub>rss</sub>			7		
Output capacitance		C <sub>oss</sub>			24	_	
Switching time	Rise time	tr	$V_{GS}^{10 \text{ V}} \downarrow_{D} = 0.25 \text{ A} \\ 0 \text{ V} \downarrow_{O} \downarrow_{O}$	_	11	_	ns
	Turn-ON time	t <sub>on</sub>		_	18	_	
	Fall time	t <sub>f</sub>		_	54	_	
	Turn-OFF time	t <sub>off</sub>		_	95	_	
Total gate charge (gate-source plus gate-drain)		Qg		_	3.8	_	nC
Gate-source charge		Q <sub>gs</sub>	V <sub>DD</sub> ≈ 400 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.5 A		1.9		
Gate-drain ("miller") charge		Q <sub>gd</sub>	]		1.9		

### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—			0.5	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	—	_	_	1.5	А
Forward voltage (diode)	V <sub>DSF</sub>	$I_{DR} = 0.5 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.5	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 0.5 \text{ A}, V_{GS} = 0 \text{ V},$	_	190	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dl <sub>DR</sub> /dt = 100 A / μs		380	—	nC

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